

2N6782 Information



For Reference Only

Part Number 2N6782

Manufacturer Microsemi Corporation

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Single

Description MOSFET N-CH 100V TO-205AF

Package TO-205AF Metal Can

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









2N6782 Specifications

Manufacturer Part Number	2N6782
Manufacturer	Microsemi Corporation
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-205AF Metal Can
Series	-
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	100V
Current - Continuous Drain (Id) @ 25°C	3.5A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4V @ 250μA
Gate Charge (Qg) (Max) @ Vgs	8.1nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	-
Vgs (Max)	±20V
FET Feature	-
Power Dissipation (Max)	800mW (Ta), 15W (Tc)
Rds On (Max) @ Id, Vgs	600 mOhm @ 2.25A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-39
Package / Case	TO-205AF Metal Can
	Report errors?

2N6782 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

2N6782 Payment Methods



















2N6782 Shipping Methods













If you have any question about 2N6782, please do not hesitate to contact us!

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